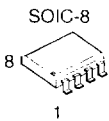


Symmetric SOIC-8 Dual/Single DMOS



- Superior performance than NDS9xxx Series.
- Special package technology to reduce package resistance.
- High cell density (5 million cells /in²) for low on-resistance.

N Channel

(Volts) Min	Device	r _{DS(on)} Max (Ω)		I _D (A) Max	P _D (Watts) Max	Configuration	Pin Out
		V _{GS} = 10V	V _{GS} = 4.5V				
20	NDS8410*	0.015	TBD	7	2.5	Single	2
20	NDS8936*	0.03	TBD	5	2	Dual	1

* Advance Information.

P Channel

(Volts) Min	Device	r _{DS(on)} Max (Ω)		I _D (A) Max	P _D (Watts) Max	Configuration	Pin Out
		V _{GS} = 10V	V _{GS} = 4.5V				
-20	NDS8330*	0.03	TBD	-5	2.5	Single	2
-20	NDS8847*	0.06	TBD	-3.5	2	Dual	1

* Advance Information.

